

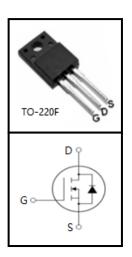
600V N-Channel MOSFET

FEATURES

- Fast switching
- 100% avalanche tested
- Improved dv/dt capability

APPLICATIONS

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)



Device Marking and Package Information			
Device	Package	Marking	
CS2N60FF	TO-220F	CS2N60FF	

Absolute Maximum Ratings $T_C = 25^{\circ}C$, unless otherwise noted				
Parameter	Symbol	Value	Unit	
Drain-Source Voltage (V _{GS} = 0V)	V _{DSS}	600	V	
Continuous Drain Current	I _D	2	Α	
Pulsed Drain Current (note1)	I _{DM}	8	А	
Gate-Source Voltage	V_{GSS}	±30	V	
Single Pulse Avalanche Energy (note2)	E _{AS}	64.8	mJ	
Avalanche Current (note1)	I _{AS}	3.6	А	
Repetitive Avalanche Energy (note1)	E _{AR}	0.26	mJ	
Power Dissipation (T _C = 25°C)	P_{D}	40.5	W	
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55~+150	°C	

Thermal Resistance			
Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	R_{thJC}	3.09	00044
Thermal Resistance, Junction-to-Ambient	R _{thJA}	62.5	°C/W



Specifications $T_J = 25^{\circ}C$, ur			Value			
Parameter	Symbol	Test Conditions	1 1		Max.	Unit
Static				7.		
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0V, I_D = 250\mu A$	600			V
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 600V, V_{GS} = 0V, T_{J} = 25^{\circ}C$			1	μA
Gate-Source Leakage	I _{GSS}	$V_{GS} = \pm 30V$			±100	nA
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	3.0		4.0	V
Drain-Source On-Resistance (Note3)	R _{DS(on)}	$V_{GS} = 10V, I_{D} = 1.0A$		4.1	4.7	Ω
Dynamic						
Input Capacitance	C _{iss}			234		
Output Capacitance	C _{oss}	$V_{GS} = 0V$,		27.5		pF
Reverse Transfer Capacitance	C _{rss}	$V_{DS} = 25V$, f = 1.0MHz		1.4		
Internal Gate Resistance	Rg			3		Ω
Total Gate Charge	Q_g			6.6		
Gate-Source Charge	Q_gs	$V_{DD} = 480V, I_{D} = 2.0A,$ $V_{GS} = 10V$		1.3		nC
Gate-Drain Charge	Q_{gd}	GS 101		4		
Turn-on Delay Time	t _{d(on)}			33.5		
Turn-on Rise Time	t _r	V _{DD} = 300V, I _D =2.0A,		6		
Turn-off Delay Time	t _{d(off)}	$R_G = 25 \Omega$		44.5		ns
Turn-off Fall Time	t _f			26.5		
Drain-Source Body Diode Character	istics					
Continuous Body Diode Current	Is	T 05.00			2	А
Pulsed Diode Forward Current	I _{SM}	T _C = 25 °C			8	A .
Body Diode Voltage	V_{SD}	$T_J = 25^{\circ}C$, $I_{SD} = 1.0A$, $V_{GS} = 0V$	-		1.4	V
Reverse Recovery Time	t _{rr}	$V_R = 300V, I_S = 2.0A,$		231		ns
Reverse Recovery Charge	Q _{rr}	di _F /dt =100A /μs		0.76		μC

Notes

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature
- 2. L = 10.0mH, V_{DD} = 50V, R_G = 25 Ω , Starting T_J = 25 $^{\circ}C$
- 3. Pulse Test: Pulse width ≤ 300µs, Duty Cycle ≤ 1%



Typical Characteristics $T_J = 25^{\circ}\text{C}$, unless otherwise noted

Figure 1. Output Characteristics ($T_J = 25^{\circ}C$)

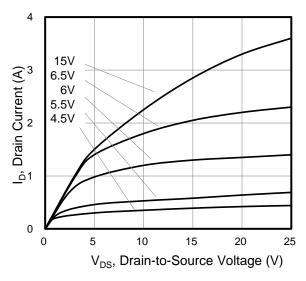


Figure 3. Drain Current vs. Temperature

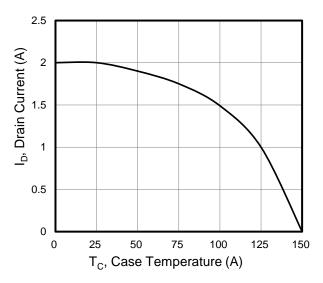


Figure 5. Transfer Characteristics

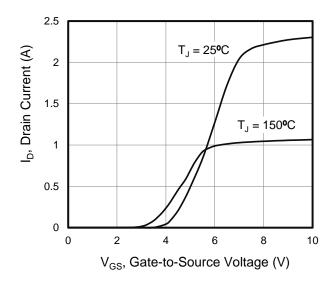


Figure 2. Body Diode Forward Voltage

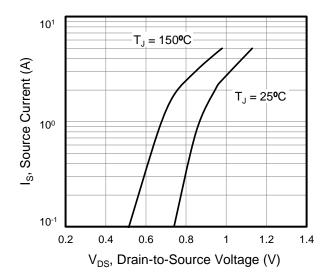


Figure 4. BV_{DSS} Variation vs. Temperature

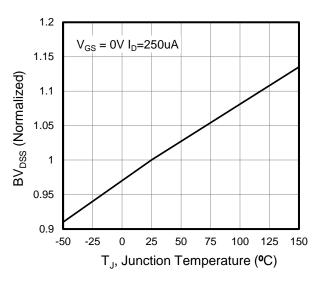
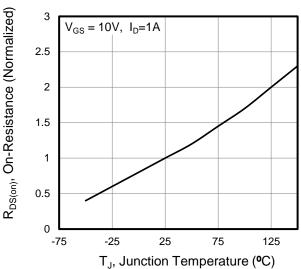


Figure 6. On-Resistance vs. Temperature





Typical Characteristics $T_J = 25^{\circ}\text{C}$, unless otherwise noted

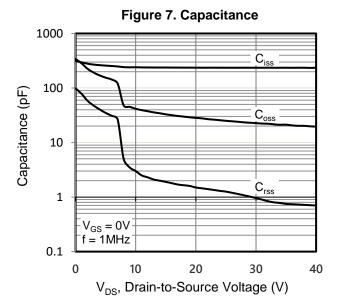


Figure 8. Gate Charge

Figure 10. Transient Thermal Impedance

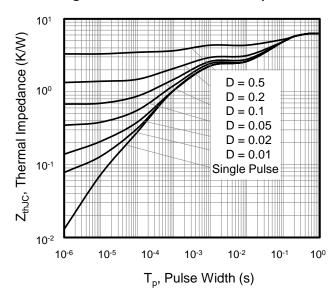




Figure A: Gate Charge Test Circuit and Waveform

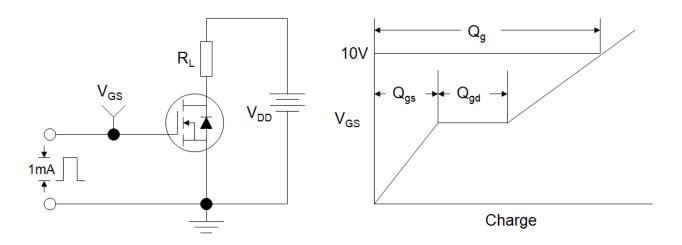


Figure B: Resistive Switching Test Circuit and Waveform

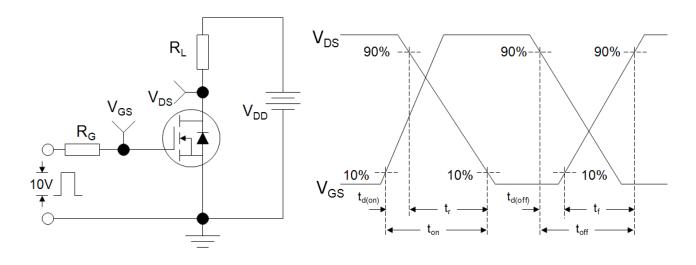
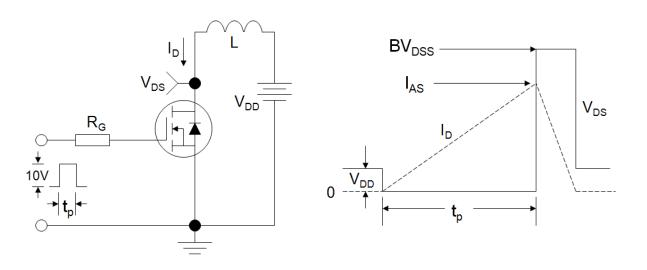
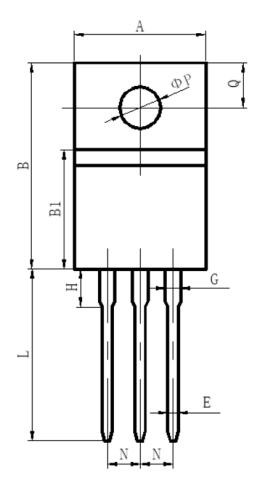


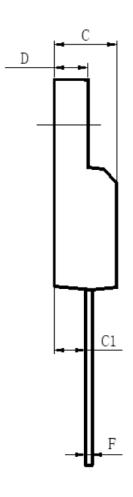
Figure C: Unclamped Inductive Switching Test Circuit and Waveform





TO-220F





SYMBOLS	MILLIMETERS		
STIVIBULS	MIN	MAX	
Α	9.70	10.30	
В	15.50	16.10	
B1	8.99	9.39	
С	4.40	4.80	
C1	2.15	2.55	
D	2.50	2.90	
E	0.70	0.90	
F	0.40	0.60	
G	1.12	1.42	
Н	3.40	3.80	
L	12.60	13.60	
N	2.34	2.74	
Q	3.15	3.55	
ФР	3.00	3.30	



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